P-Channel Enhancement Mode Power MOSFET

MTA600P02KSN3

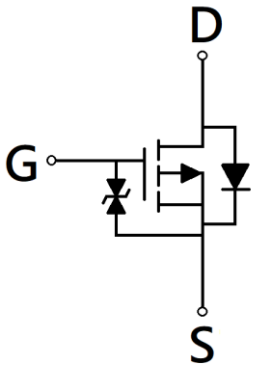
Features

- Low On Resistance
- Low Gate Charge
- Fast Switching Characteristic
- ESD protected gate, typical 4kV (HBM)

BV_{DSS}	-20V
I_D@V_{GS}=-4.5V, T_A=25°C	-0.62A
$R_{DS(ON)}$ typ. @ V_{GS}=-4.5V, I_D=-0.2A	0.75Ω
$R_{DS(ON)}$ typ. @ V_{GS}=-2.5V, I_D=-0.2A	0.9Ω
$R_{DS(ON)}$ typ. @ V_{GS}=-1.8V, I_D=-10mA	1.1Ω

Equivalent Circuit

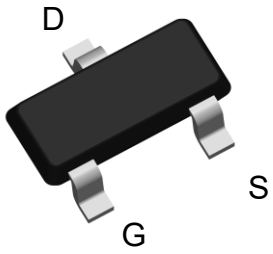
MTA600P02KSN3



G : Gate S : Source D : Drain

Outline

SOT-23



Ordering Information

Device	Package	Shipping
MTA600P02KSN3-0-T1-G	SOT-23 (Pb-free lead plating and halogen-free package)	3000 pcs / tape & reel

Environment friendly grade : S for RoHS compliant products, G for RoHS compliant and green compound products

Packing spec, T1 : 3000 pcs / tape & reel,7" reel

Product rank, zero for no rank products

Product name

Absolute Maximum Ratings (T_A=25°C)

Parameter		Symbol	Limits	Unit
Drain-Source Voltage		V_{DS}	-20	V
Gate-Source Voltage		V_{GS}	±8	
Continuous Drain Current @ V_{GS}=-4.5V, T_A=25°C		I_D	-0.62	A
Continuous Drain Current @ V_{GS}=-4.5V, T_A=70°C			-0.5	
Pulsed Drain Current	*a	I_{DM}	-2.5	
Continuous Body Diode Forward Current @ T_A=25°C		I_S	-0.56	
ESD susceptibility	*b	V_{ESD}	4000	V
Total Power Dissipation	T_A=25°C	P_D	0.69	W
	T_A=70°C		0.44	
Operating Junction and Storage Temperature Range		T_J, T_{stg}	-55~+150	°C

Thermal Data

Parameter	Symbol	Steady State	Unit
Thermal Resistance, Junction-to-ambient	$R_{\theta JA}$	181	°C/W

Note:
*a. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and low duty cycles to keep initial TJ=25°C.
*b. Human body model, 1.5kΩ in series with 100pF.

Electrical Characteristics (T_A=25°C, unless otherwise specified)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Static					
BV_{DSS}	-20	-	-	V	V_{GS}=0V, I_D=-250μA
$V_{GS(th)}$	-0.4	-	-1.2		V_{DS}=V_{GS}, I_D=-250μA
G_{FS}	-	1	-	S	V_{DS}=-5V, I_D=-0.4A
I_{GSS}	-	-	±10	μA	V_{GS}=±8V, V_{DS}=0V
I_{DSS}	-	-	-1		V_{DS}=-16V, V_{GS}=0V
$R_{DS(ON)}$	-	0.75	1.1	Ω	V_{GS}=-4.5V, I_D=-0.2A
	-	0.9	1.5		V_{GS}=-2.5V, I_D=-0.2A
	-	1.1	2.5		V_{GS}=-1.8V, I_D=-10mA
Dynamic					
Ciss	-	45	-	pF	V_{DS}=-10V, V_{GS}=0V, f=1MHz
Coss	-	15	-		
Crss	-	5.6	-		
Qg *1, 2	-	1	-	nC	V_{DS}=-20V, I_D=-0.4A, V_{GS}=-4.5V
Qgs *1, 2	-	0.2	-		
Qgd *1, 2	-	0.2	-		
$t_{d(ON)}$ *1, 2	-	11	-	ns	V_{DS}=-15V, I_D=-0.4A, V_{GS}=-4.5V, R_{GS}=1Ω
tr *1, 2	-	19	-		
$t_{d(OFF)}$ *1, 2	-	43	-		
t_f *1, 2	-	28	-		
Source-Drain Diode					
V_{SD} *1	-	-0.92	-1.2	V	I_S=-0.4A, V_{GS}=0V
trr	-	25	-	ns	I_F=-0.5A, dI_F/dt=100A/μs
Qrr	-	5	-	nC	

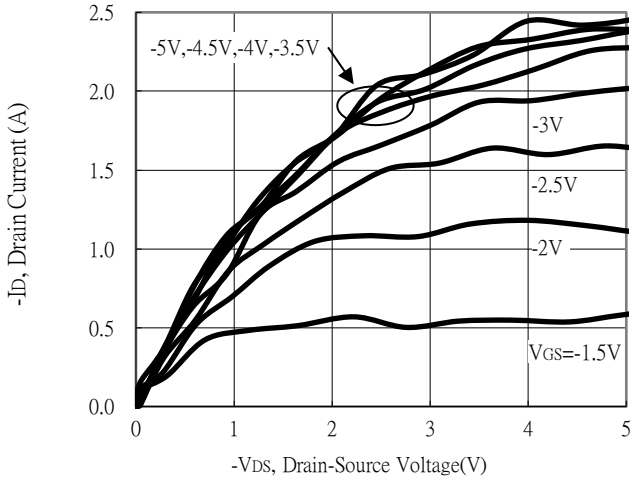
Note:

*1. Pulse Test : Pulse Width ≤300μs, Duty Cycle≤2%

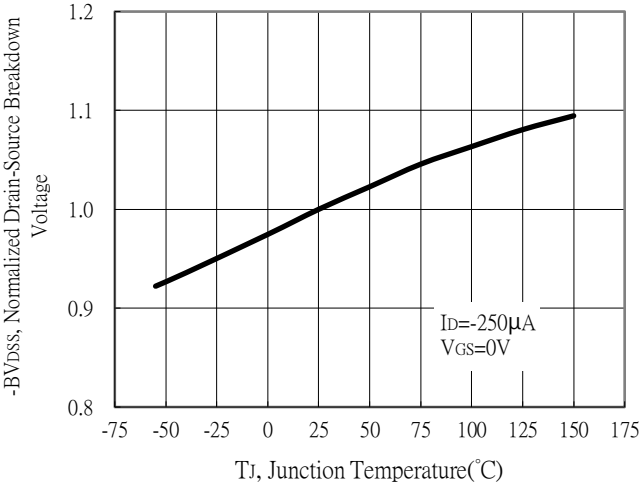
*2. Independent of operating temperature

Typical Characteristics

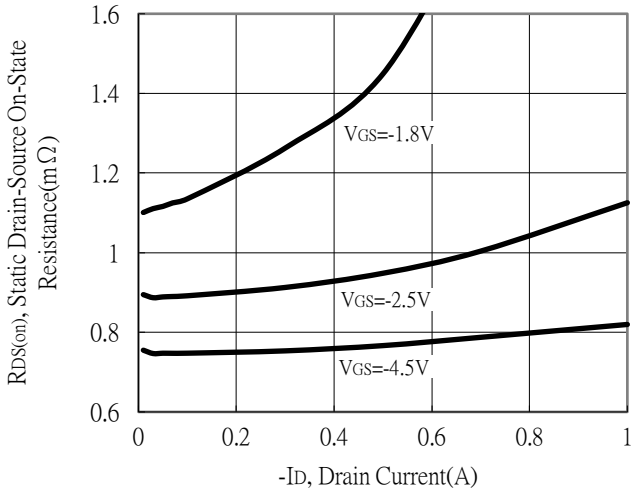
Typical Output Characteristics



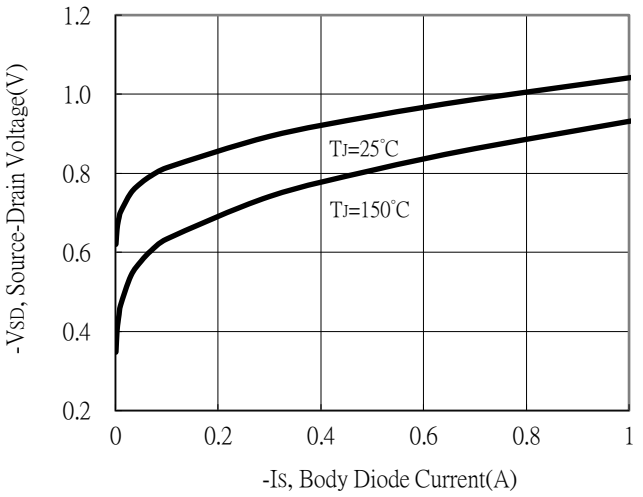
Breakdown Voltage vs Junction Temperature



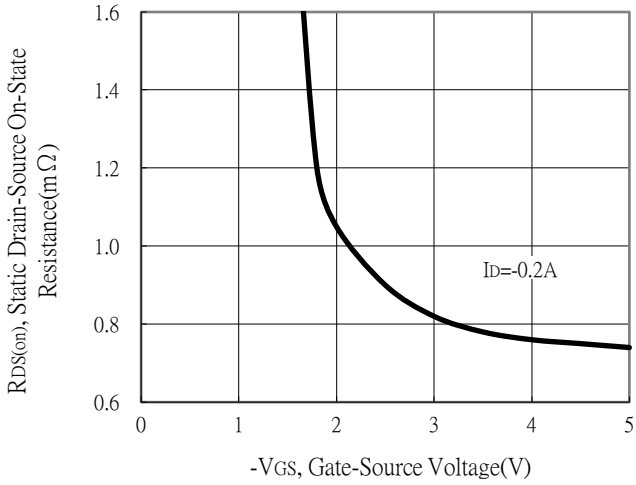
Static Drain-Source On-State resistance vs Drain Current



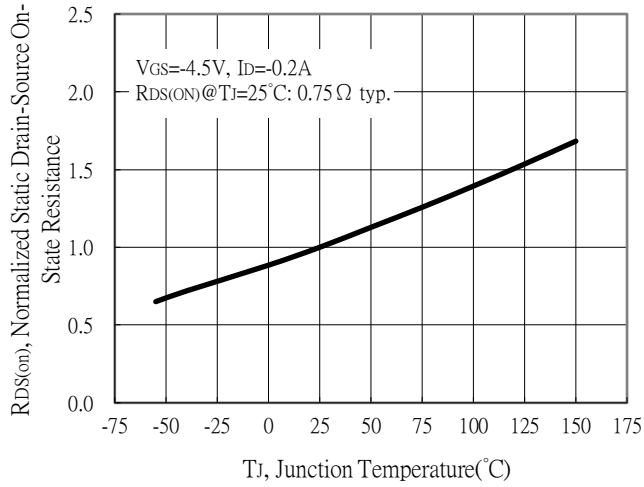
Body Diode Current vs Source-Drain Voltage



Static Drain-Source On-State Resistance vs Gate-Source Voltage

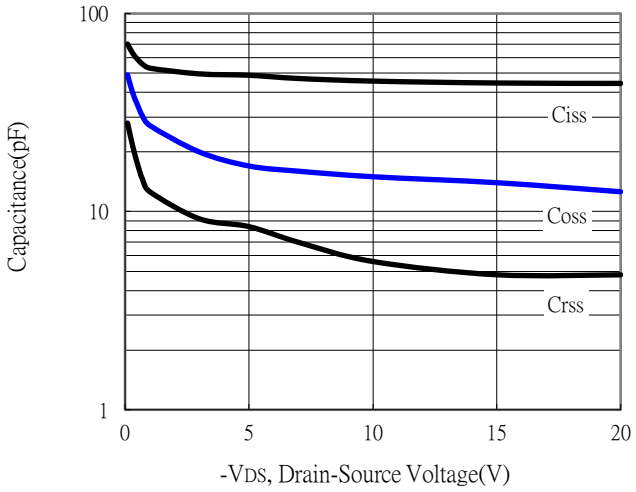


Drain-Source On-State Resistance vs Junction Temperature

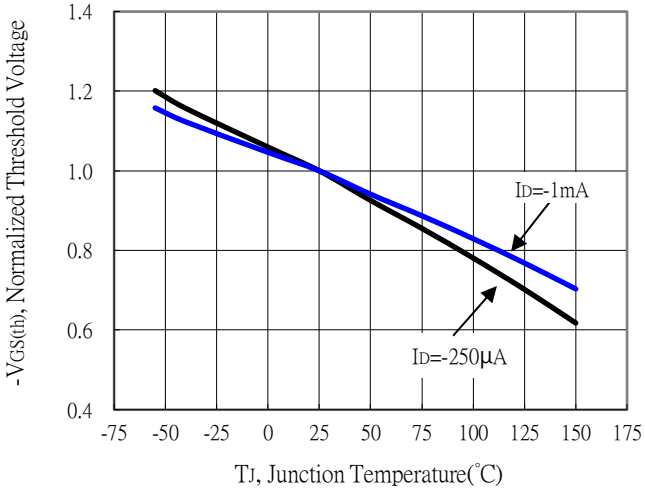


Typical Characteristics (Cont.)

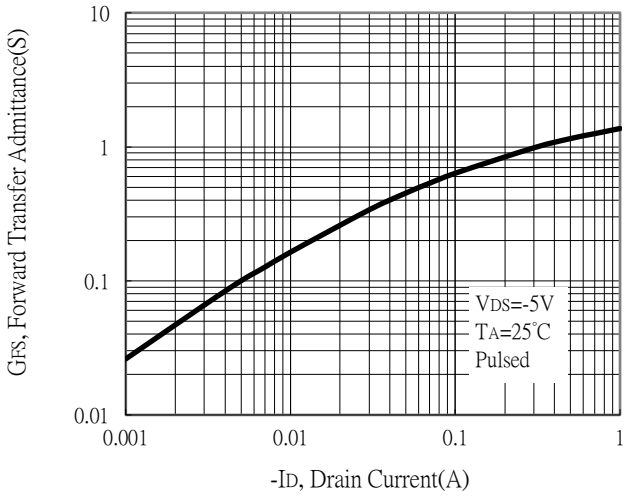
Capacitance vs Drain-to-Source Voltage



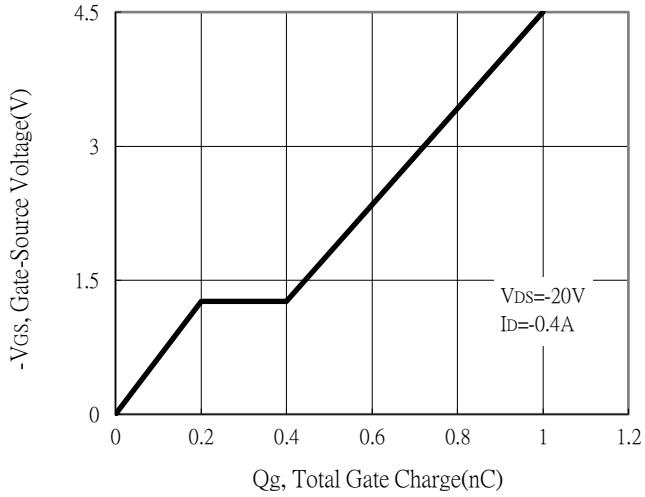
Threshold Voltage vs Junction Temperature



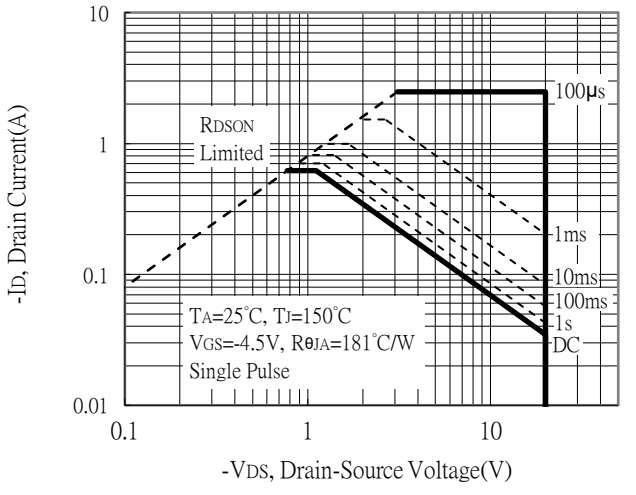
Forward Transfer Admittance vs Drain Current



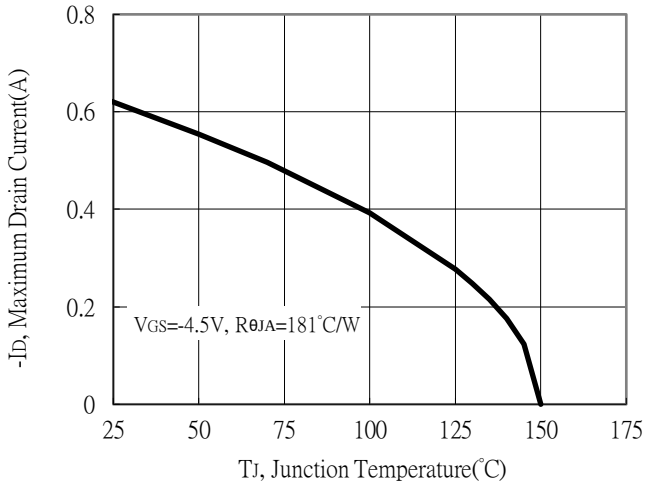
Gate Charge Characteristics



Maximum Safe Operating Area

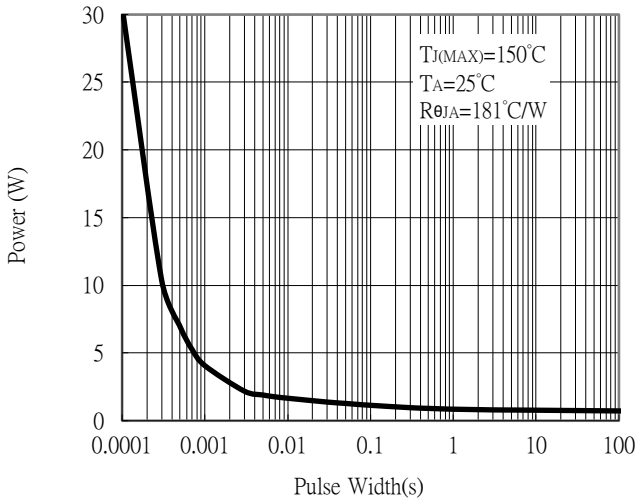


Maximum Drain Current vs Junction Temperature

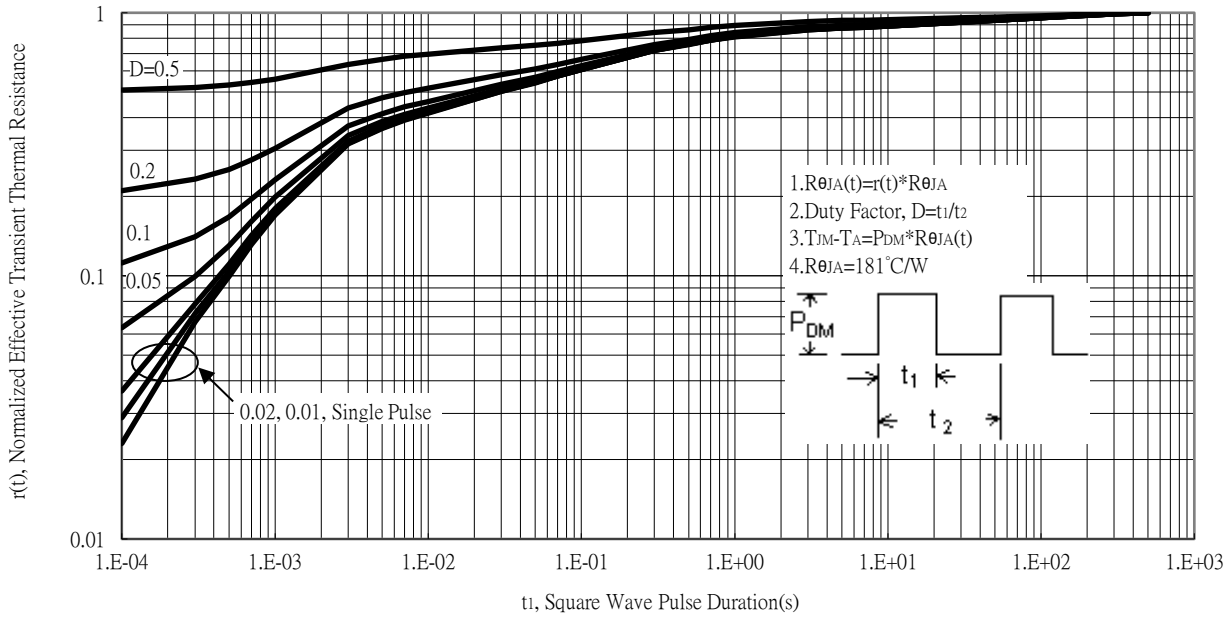


Typical Characteristics (Cont.)

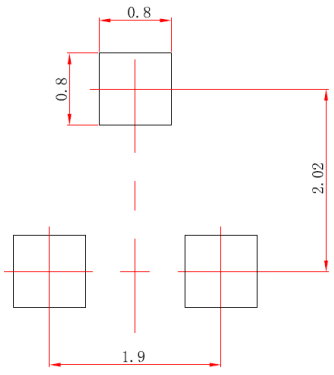
Single Pulse Power Rating, Junction to Ambient



Transient Thermal Response Curves

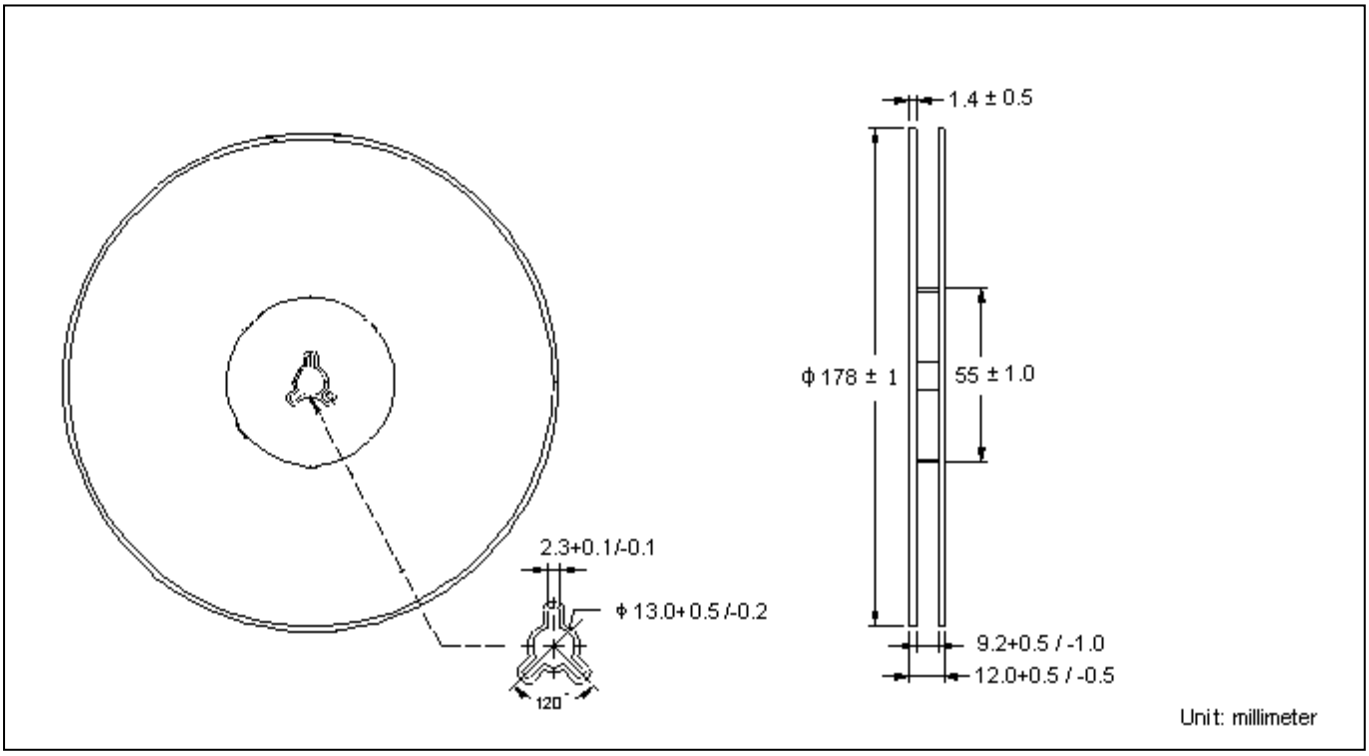


Recommended Soldering Footprint

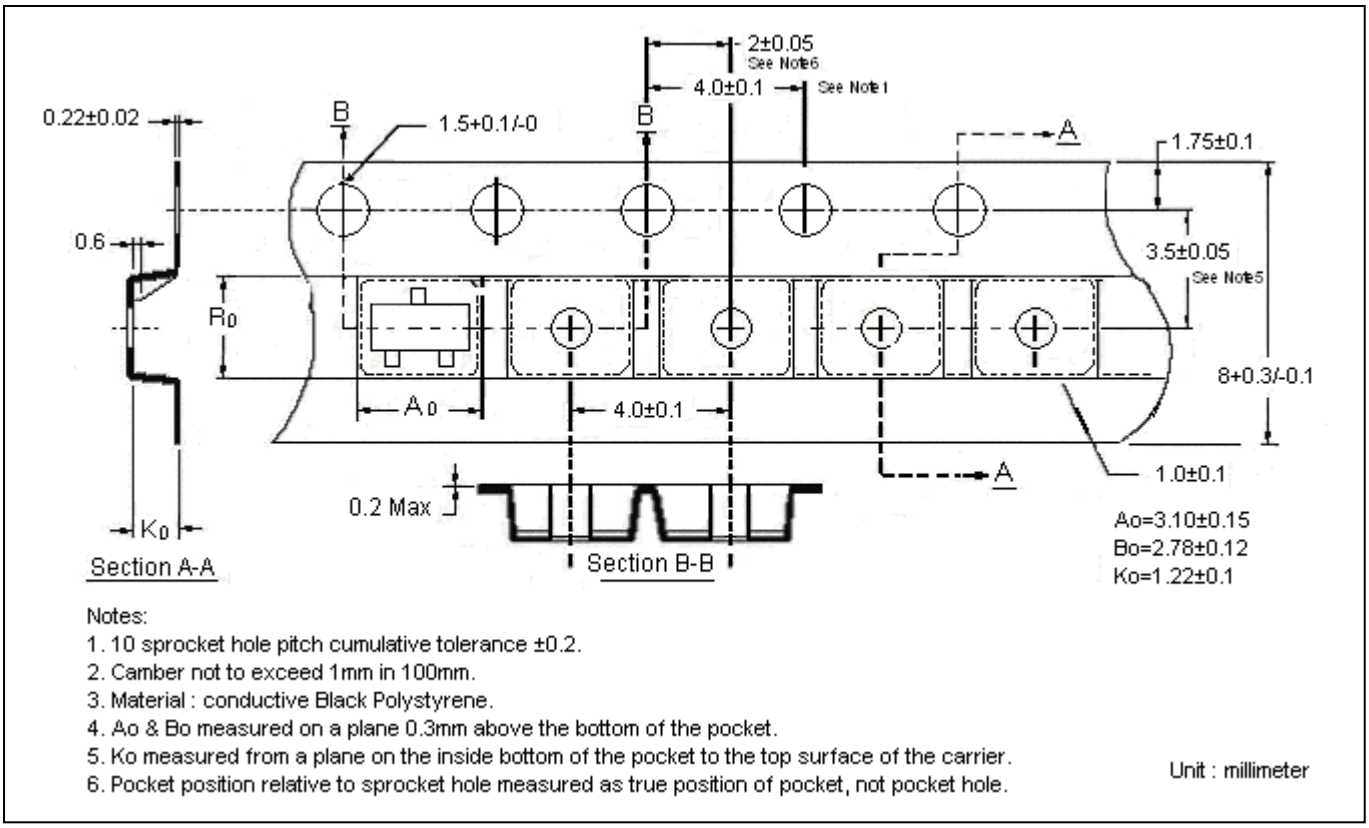


unit:mm

Reel Dimension



Carrier Tape Dimension



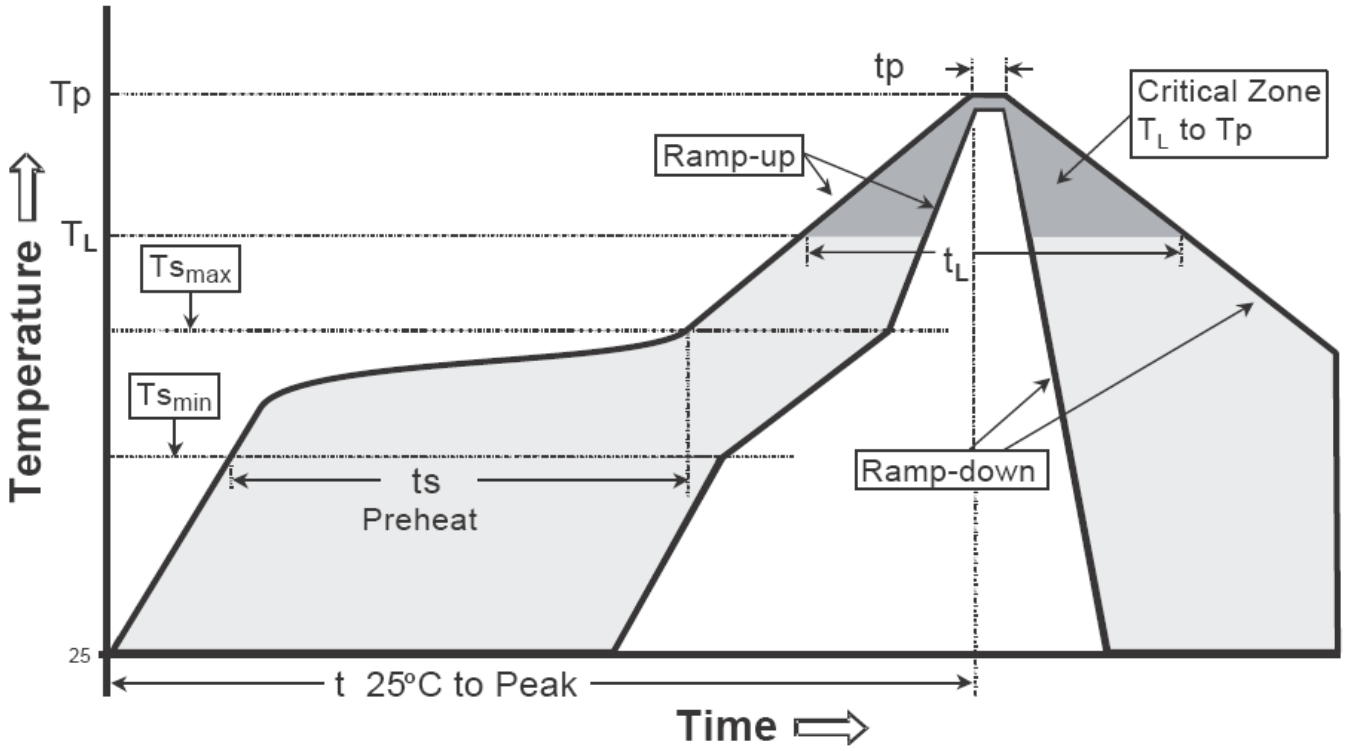
Notes:
1. 10 sprocket hole pitch cumulative tolerance ±0.2.
2. Camber not to exceed 1mm in 100mm.
3. Material : conductive Black Polystyrene.
4. Ao & Bo measured on a plane 0.3mm above the bottom of the pocket.
5. Ko measured from a plane on the inside bottom of the pocket to the top surface of the carrier.
6. Pocket position relative to sprocket hole measured as true position of pocket, not pocket hole.

Unit : millimeter

Recommended wave soldering condition

Product	Peak Temperature	Soldering Time
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds

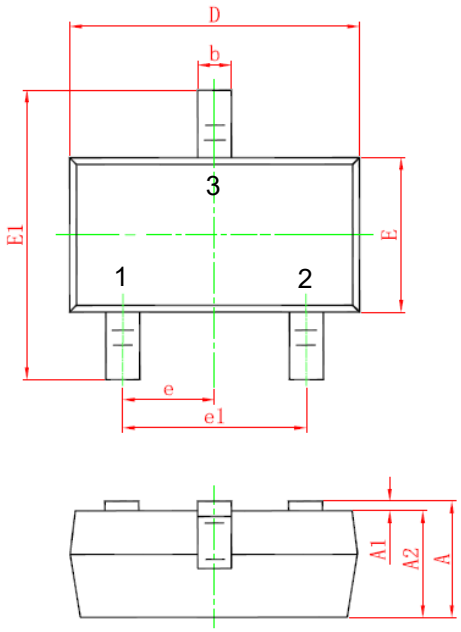
Recommended temperature profile for IR reflow

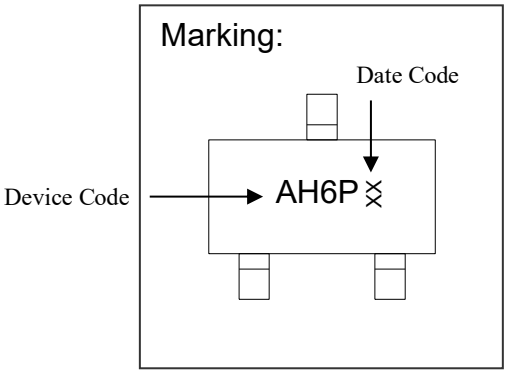


Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly
Average ramp-up rate (Tsmax to Tp)	3°C/second max.	3°C/second max.
Preheat −Temperature Min(Ts min) −Temperature Max(Ts max) −Time(ts min to ts max)	 100°C 150°C 60-120 seconds	 150°C 200°C 60-180 seconds
Time maintained above: −Temperature (TL) − Time (tL)	 183°C 60-150 seconds	 217°C 60-150 seconds
Peak Temperature(TP)	240 +0/-5 °C	260 +0/-5 °C
Time within 5°C of actual peak temperature(tp)	10-30 seconds	20-40 seconds
Ramp down rate	6°C/second max.	6°C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

Note : All temperatures refer to topside of the package, measured on the package body surface.

SOT-23 Dimension





3-Lead SOT-23 Plastic
Surface Mounted Package
CYStek Package Code: N3

Style: Pin 1.Gate 2.Source 3.Drain

Date Code: Year+Month
Year: 3→2003, 4→2004
Month: 1→1, 2→2, • • •
9→9, A→10, B→11, C→12

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.035	0.045	0.900	1.150	E1	0.089	0.100	2.250	2.550
A1	0.000	0.004	0.000	0.100	e	0.037 TYP		0.950 TYP	
A2	0.035	0.041	0.900	1.050	e1	0.071	0.079	1.800	2.000
b	0.012	0.020	0.300	0.500	L	0.022 REF		0.550 REF	
c	0.003	0.006	0.080	0.150	L1	0.012	0.020	0.300	0.500
D	0.110	0.118	2.800	3.000	θ	0°	8°	0°	8°
E	0.047	0.055	1.200	1.400					

Notes: 1.Controlling dimension: millimeters.
2.Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.
3.If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material:

- Lead: Pure tin plated.
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0.